

ADA4097-1/ADA4097-2

50 V, 130 kHz, 32.5 μA per Channel, Robust, Over-The-Top, Precision Op Amps

FEATURES

- ▶ Ultrawide common-mode input range: $-V_S 0.1 \text{ V}$ to $-V_S + 70 \text{ V}$
- ▶ Wide power supply voltage range: +3 V to +50 V (to ±25 V for PSRR)
- ▶ Low power supply current: 32.5 µA (typical)
- ► Low input offset voltage: ±60 µV maximum
- Low input offset voltage drift: ±1 μV/°C maximum (B grade)
- ▶ Low input voltage noise
 - ▶ 6 Hz typical 1/f noise corner
- ▶ 1000 nV p-p typical at 0.1 Hz to 10 Hz
- ▶ GBP: 130 kHz typical for f_{TEST} = 250 Hz
- Slew rate: 0.1 V/μs typical at ΔV_{OUT} = 4 V
- Low power supply current shutdown: 20 μA maximum
- ▶ Low input offset current: ±300 pA maximum
- ▶ Large signal voltage gain: 120 dB minimum for $\Delta V_{OUT} = 3.5 \text{ V}$
- ▶ CMRR: 120 dB minimum at $V_{CM} = -0.1 \text{ V to } +70 \text{ V}$
- \triangleright PSRR: 123 dB minimum at V_{SY} = +3 V to ±25 V
- ▶ Input overdrive tolerant with no phase reversal
- ▶ ±2 kV HBM and ±1.25 kV FICDM
- ▶ Wide temperature range: -55°C to +150°C (H grade)
- ▶ Shutdown feature available for single 6-lead TSOT and dual 10-lead LFCSP packages

APPLICATIONS

- Industrial sensor conditioning
- ▶ Supply current sensing

TYPICAL APPLICATION CIRCUIT

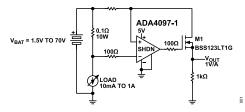


Figure 1. 1 V/A Over-The-Top Current Sense Application (V_{BAT} Is the Battery Voltage.)

- Battery and power supply monitoring
- ▶ Front-end amplifiers in abusive environments
- ▶ 4 mA to 20 mA transmitters

GENERAL DESCRIPTION

The ADA4097-1/ADA4097-2 are single and dual robust, precision, rail-to-rail input and output operational amplifiers (op amps) with inputs that operate from $-\text{V}_S$ to $+\text{V}_S$ and beyond, which are referred to in this data sheet as Over-The-Top $^{\text{TM}}$. The devices feature offset voltages of <60 μV , input bias currents (IB) of <0.3 nA, and can operate on single or split supplies that range from 3 V to 50 V. The ADA4097-1/ADA4097-2 draw 32.5 μA of supply current per channel.

The ADA4097-1/ADA4097-2 Over-The-Top $^{\text{TM}}$ input stages have robust input protection features for abusive environments. The inputs can tolerate up to 80 V of differential voltage without damage or degradation to dc accuracy. The operating common-mode input range extends from rail-to-rail and beyond, up to 70 V > -V $_S$, independent of the +V $_S$ supply.

The ADA4097-1/ADA4097-2 are unity-gain stable and can drive loads requiring up to 20 mA per channel. The devices can also drive capacitive loads as large as 200 pF. The amplifiers are available with low power shutdown.

The ADA4097-1 is available in a standard, 6-lead thin small outline transistor (TSOT) package. The ADA4097-2 is available in an 8-lead standard small outline (SOIC_N) package, 8-lead mini small outline package (MSOP), and 10-lead lead-frame chip-scale package (LFCSP).

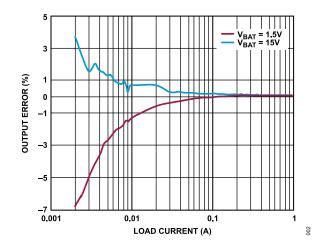


Figure 2. Output Error vs. Load Current

Rev. A



Information furnished by Analog Devices is believed to be accurate and reliable "as is". However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

Rev. A | 2 of 31

TABLE OF CONTENTS

Footures 1	Output	20
Features	Shutdown Pins (SHDN and SHDNx)	
General Description1	Applications Information	
Typical Application Circuit1	Large Resistor Gain Operation	
Specifications	Recommended Values for Various Gains	
5 V Supply3	Noise	
±15 V Supply5	Distortion	
Absolute Maximum Ratings8	Power Dissipation and Thermal Shutdown	
Maximum Power Dissipation8	Circuit Layout Considerations	
Thermal Resistance8	Power Supply Bypassing	
Electrostatic Discharge (ESD) Ratings8	Grounding	25
ESD Caution9	ESD Protection when Powered	
Pin Configurations and Function Descriptions10	Related Products	
Typical Performance Characteristics	Typical Applications	
Theory of Operation	Outline Dimensions	
Input Protection21	Ordering Guide	
Over-The-Top Operation Considerations 21	Evaluation Boards	
REVISION HISTORY		
4/2022—Rev. 0 to Rev. A		
Added ADA4097-2, 8-Lead SOIC_N, 8-Lead MSOP, as	nd 10-l ead LFCSP	1
Changes to Data Sheet Title		
Changes to Features		
Changes to General Description Section		
Changes to 5 V Supply Section and Table 1		
Changes to ±15 V Supply Section and Table 2		
Changes to Table 3		
Changes to Maximum Power Dissipation Section		
Changes to Thermal Resistance Section and Table 4		
Changes to Table 5 and Table 5 Title		
Changes to Figure 4 Caption and Table 6 Title		
Added Figure 5, Table 7, Figure 6, and Table 8; Renum		
Changes to Figure 56		
Changes to Output Section		
Changes to Shutdown Pins (SHDN and SHDNx) Section		
Changes to Power Dissipation and Thermal Shutdown		
Changes to Power Supply Bypassing Section		
Changes to Table 10		
Added Figure 75, Figure 76, and Figure 77		
Added Evaluation Boards Section		

5/2021—Revision 0: Initial Version

5 V SUPPLY

Common-mode voltage (V_{CM}) = 2.5 V, SHDN pin (ADA4097-1) and SHDNx pins (ADA4097-2 the 10-lead LFCSP only) are open, load resistance (R_{LOAD}) = 499 k Ω to midsupply, and T_A = 25°C, unless otherwise noted.

Table 1.

			B Grade	•		H Grade		
Parameter	Test Conditions/Comments	Min	Тур	Max	Min	Тур	Max	Unit
DC PERFORMANCE								
Input Offset Voltage (V _{OS}) ¹	0.25 V < V _{CM} < 3.25 V		±20	±60		±20	±60	μV
				±130			±160	μV
	0.25 V < V _{CM} < 70 V		±30	±60		±30	±60	μV
	$T_{MIN} < T_A < T_{MAX}$			±160			±185	μV
	-0.1 V < V _{CM} < +70 V		±30	±60		±30	±60	μV
	$T_{MIN} < T_A < T_{MAX}$			±550			±600	μV
Input Offset Voltage Drift ²	$T_{MIN} < T_A < T_{MAX}$		±0.1	±1		±0.1	±1.5	μV/°C
Input Bias Current (I _B)			±0.1	±0.3		±0.1	±0.3	nA
	$T_{MIN} < T_A < T_{MAX}$			±10			±25	nA
	V _{CM} = 70 V, Over-The-Top	0.25	0.8	1.5	0.25	8.0	1.5	μA
	$T_{MIN} < T_A < T_{MAX}$	0.175		2.25	0.125		2.5	μA
	$0 \text{ V} < \text{V}_{\text{CM}} < 70 \text{ V}, \text{V}_{\text{SY}} = 0 \text{ V}$		0.001	1		0.001	1	μA
	$T_{MIN} < T_A < T_{MAX}$			10			10	μA
Input Offset Current (I _{OS})			±100	±300		±100	±300	pA
	$T_{MIN} < T_A < T_{MAX}$			±5			±10	nA
	V _{CM} = 70 V, Over-The-Top ³		±0.025	±0.065		±0.025	±0.065	μA
	$T_{MIN} < T_A < T_{MAX}$			±0.095			±0.2	μA
Common-Mode Rejection Ratio (CMRR)	$V_{CM} = -0.1 \text{ V to } +70 \text{ V}$	120	145		120	145		dB
	$T_{MIN} < T_A < T_{MAX}$	101			100			dB
	V _{CM} = 0.25 V to 3.25 V	115	134		115	134		dB
	$T_{MIN} < T_A < T_{MAX}$	110			107			dB
Common-Mode Input Range	Guaranteed by CMRR tests	-0.1		+70	-0.1		+70	V
Large Signal Voltage Gain (A _{OL})	Delta output voltage (ΔV_{OUT}) = 3.5 V	120	140		120	140		dB
	$T_{MIN} < T_A < T_{MAX}$	114			112			dB
	ΔV_{OUT} = 3.5 V, R _{LOAD} = 10 k Ω	96	108		96	108		dB
	$T_{MIN} < T_A < T_{MAX}$	90			86			dB
NOISE PERFORMANCE								
Input Voltage Noise	Frequency (f) = 0.1 Hz to 10 Hz		1000			1000		nV p-p
	1/f noise corner		6			6		Hz
	f = 100 Hz		53			53		nV/√Hz
Over-The-Top	f = 100 Hz, V _{CM} > 5 V		65			65		nV/√Hz
Input Current Noise	f = 100 Hz		0.05			0.05		pA/√Hz
Over-The-Top	f = 100 Hz, V _{CM} > 5 V		0.5			0.5		pA/√Hz
DYNAMIC PERFORMANCE								
Slew Rate	$\Delta V_{OUT} = 4 V$	0.025	0.1		0.025	0.1		V/µs
	$T_{MIN} < T_A < T_{MAX}$	0.018			0.015			V/µs
Gain Bandwidth Product (GBP)	Test frequency (f _{TEST}) = 250 Hz	120	130		120	130		kHz
	$T_{MIN} < T_A < T_{MAX}$	100			100			kHz
Phase Margin			58			58		Degree

analog.com Rev. A | 3 of 31

Table 1.

			B Grad	е		H Grad	е	_
Parameter	Test Conditions/Comments	Min	Тур	Max	Min	Тур	Max	Unit
1% Settling Time	$\Delta V_{OUT} = \pm 2 V$		70			70		μs
0.1% Settling Time	$\Delta V_{OUT} = \pm 2 V$		100			100		μs
Total Harmonic Distortion Plus Noise (THD + N)	f = 1 kHz, V_{OUT} = 2 V p-p, R_{LOAD} = 10 kΩ, bandwidth = 80 kHz		0.05			0.05		%
Channel Separation	$f = 1 \text{ kHz}, R_{LOAD} = 2 \text{ k}\Omega$		115			115		dB
NPUT CHARACTERISTICS								
Input Resistance	Differential mode		10			10		MΩ
	Common mode		>1			>1		GΩ
Over-The-Top	Differential mode, V _{CM} > 5 V		60			60		kΩ
	Common mode, V _{CM} > 5 V		>1			>1		GΩ
Input Capacitance	Differential mode		1			1		pF
	Common mode		3			3		pF
SHDN AND SHDNx PINS								
Input Logic Low	Amplifier active, SHDN and SHDNx pin voltage (V _{SHDN}) < -V _S + 0.5 V, T _{MIN} < T _A < T _{MAX}			-V _S + 0.5			-V _S + 0.5	V
Input Logic High	Amplifier shutdown, V _{SHDN} > -V _S + 1.5 V, T _{MIN} < T _A < T _{MAX}	-V _S + 1.5			-V _S + 1.5			V
Response Time	Amplifier active to shutdown		2.5			2.5		μs
	Amplifier shutdown to active		100			100		μs
Pull-Down Current	$V_{SHDN} = -V_S + 0.5 \text{ V}, T_{MIN} < T_A < T_{MAX}$		0.6	3		0.6	3	μA
	V_{SHDN} = $-V_S$ + 1.5 V, T_{MIN} < T_A < T_{MAX}		0.3	2.5		0.3	2.5	μA
OUTPUT CHARACTERISTICS								
Output Voltage Swing Low	Overdrive voltage (V _{OD} ⁴) = 30 mV, no load		15	40		15	40	mV
	$T_{MIN} < T_A < T_{MAX}$			45			50	mV
	V _{OD} = 30 mV, sink current (I _{SINK}) = 5 mA		240	325		240	325	mV
	$T_{MIN} < T_A < T_{MAX}$			380			400	mV
Output Voltage Swing High	V _{OD} = 30 mV, no load		2.5	5		2.5	5	mV
	$T_{MIN} < T_A < T_{MAX}$			10			15	mV
	V _{OD} = 30 mV, source current (I _{SOURCE}) = 5 mA		570	700		570	700	mV
	$T_{MIN} < T_A < T_{MAX}$			1000			1100	mV
Short-Circuit Current	I _{SOURCE}	20	30		20	30		mA
	$T_{MIN} < T_A < T_{MAX}$	10			6			mA
	I _{SINK}	35	40		35	40		mA
	$T_{MIN} < T_A < T_{MAX}$	10			6			mA
Output Pin Leakage During Shutdown	$V_{SHDN} = -V_S + 1.5 V$		±5	±100		±5	±100	nA
	$T_{MIN} < T_A < T_{MAX}$			±10			±10	μA
POWER SUPPLY								
Maximum Operating Voltage ⁵				50			50	V
V _{SY} Range	Guaranteed by power supply rejection ratio (PSRR)	3		50	3		50	V
Supply Current per Channel	Amplifier active		32.5	36		32.5	36	μA
	$T_{MIN} < T_A < T_{MAX}$			55			60	μA

analog.com Rev. A | 4 of 31

Table 1.

	Test Conditions/Comments		B Grad	de		H Grade			
Parameter		Min	Тур	Max	Min	Тур	Max	Unit	
	Amplifier shutdown,V _{SHDN} = -V _S + 1.5 V		12	20		12	20	μA	
	$T_{MIN} < T_A < T_{MAX}$			22.5			22.5	μA	
PSRR	$V_{SY} = +3 \text{ V to } \pm 25 \text{ V}$	123	145		123	145		dB	
	$T_{MIN} < T_A < T_{MAX}$	120			120			dB	
THERMAL SHUTDOWN ⁶									
Temperature	T _J		175			175		°C	
Hysteresis			20			20		°C	
Operating Temperature	T _A	-40		+125	-55		+150	°C	

¹ Thermoelectric voltages present in the high speed production test limit the measurement accuracy of this parameter. The limits shown in Table 1 are determined by test capability and are not necessarily indicative of actual device performance.

±15 V SUPPLY

 V_{CM} = 0 V, SHDN pin (ADA4097-1) and SHDNx pins (ADA4097-2 for the 10-lead LFCSP only) are open, R_{LOAD} = 499 k Ω to ground, and T_A = 25°C, unless otherwise noted.

Table 2.

			B Grad	le		H Grade			
Parameter	Test Conditions/Comments	Min	Тур	Max	Min	Тур	Max	Unit	
DC PERFORMANCE									
V_{OS}^{1}			±20	±60		±20	±60	μV	
	$T_{MIN} < T_{A} < T_{MAX}$			±150			±175	μV	
	V _{SY} = ±25 V		±20	±60		±20	±60	μV	
	$T_{MIN} < T_A < T_{MAX}$			±150			±175	μV	
Input Offset Voltage Drift ²	$T_{MIN} < T_A < T_{MAX}$		±0.1	±1		±0.1	±1.5	μV/°C	
Input Bias Current (I _B)			±0.1	±0.3		±0.1	±0.3	nA	
	$T_{MIN} < T_A < T_{MAX}$			±10			±25	nA	
	V _{SY} = ±25 V		±0.1	±0.3		±0.1	±0.3	nA	
	$T_{MIN} < T_A < T_{MAX}$			±10			±25	nA	
los			±0.1	±0.3		±0.1	±0.3	nA	
	$T_{MIN} < T_A < T_{MAX}$			±5			±10	nA	
	V _{SY} = ±25 V		±0.1	±0.3		±0.1	±0.3	nA	
	$T_{MIN} < T_A < T_{MAX}$			±5			±10	nA	
CMRR	$V_{CM} = -14.75 \text{ V to } +13.25 \text{ V}$	117	135		117	135		dB	
	$T_{MIN} < T_A < T_{MAX}$	109			109			dB	
	$V_{CM} = -15.1 \text{ V to } +13.25 \text{ V}$	117	135		117	135		dB	
	$T_{MIN} < T_A < T_{MAX}$	93			92			dB	
	$V_{CM} = -15.1 \text{ V to } +55 \text{ V}$	117	140		117	140		dB	
	$T_{MIN} < T_A < T_{MAX}$	101			100			dB	

analog.com Rev. A | 5 of 31

² Offset voltage drift is guaranteed through lab characterization and is not production tested.

³ Test accuracy is limited by high speed production test equipment repeatability. Bench measurements indicate that the input offset current in Over-The-Top configuration is typically controlled to under 50 nA at +25°C and 100 nA over the −55°C < T_A < +150°C temperature range.

 $^{^4}$ $\,$ V_{OD} is +30 mV for V_{OUT} high and –30 mV for V_{OUT} low.

Maximum operating voltage is limited by the time-dependent dielectric breakdown (TDDB) of the on-chip capacitor oxides. The amplifier tolerates temporary transient overshoot up to the specified absolute maximum rating, but the dc supply voltage must be limited to the maximum operating voltage.

⁶ Thermal shutdown is lab characterized only and is not tested in production.

Table 2.

			B Grad	е		H Grad	le	
Parameter	Test Conditions/Comments	Min	Тур	Max	Min	Тур	Max	Unit
Common-Mode Input Range	Guaranteed by CMRR tests	-15.1		+55	-15.1		+55	V
A_{OL}	$\Delta V_{OUT} = 25 \text{ V}$	120	150		120	150		dB
	$T_{MIN} < T_A < T_{MAX}$	114			112			dB
	ΔV_{OUT} = 25 V, R _{LOAD} =10 k Ω	100	108		100	108		dB
	$T_{MIN} < T_{A} < T_{MAX}$	94			90			dB
NOISE PERFORMANCE								
Input Voltage Noise	f = 0.1 Hz to 10 Hz		1000			1000		nV p-p
	1/f noise corner		6			6		Hz
	f = 100 Hz		53			53		nV/√Hz
Over-The-Top	f = 100 Hz, V _{CM} > +V _S		65			65		nV/√Hz
Input Current Noise	f=100 Hz		0.05			0.05		pA/√Hz
Over-The-Top	f = 100 Hz, V _{CM} > +V _S		0.5			0.5		pA/√Hz
DYNAMIC PERFORMANCE								
Slew Rate	$\Delta V_{OUT} = 25 \text{ V}$	0.03	0.1		0.03	0.1		V/µs
	$T_{MIN} < T_A < T_{MAX}$	0.02			0.015			V/µs
GBP	f _{TEST} = 250 Hz	125	130		125	130		kHz
	$T_{MIN} < T_A < T_{MAX}$	100			100			kHz
Phase Margin			59			59		Degrees
1% Settling Time	$\Delta V_{OUT} = \pm 2 V$		70			70		μs
0.1% Settling Time	$\Delta V_{OUT} = \pm 2 V$		100			100		μs
THD + N	f = 1 kHz, V_{OUT} = 5.6 V p-p, R_{LOAD} = 10 kΩ, bandwidth = 80 kHz		0.1			0.1		%
Channel Separation	$f = 1 \text{ kHz}, R_{LOAD} = 2 \text{ k}\Omega$		115			115		dB
NPUT CHARACTERISTICS								
Input Resistance	Differential mode		10			10		МΩ
	Common mode		>1			>1		GΩ
Input Capacitance	Differential mode		1			1		pF
	Common mode		3			3		pF
SHDN AND SHDNx PINS								
Input Logic Low	Amplifier active, V _{SHDN} < -V _S + 0.5 V			$-V_S + 0.5$			$-V_S + 0.5$	V
Input Logic High	Amplifier shutdown, $V_{SHDN} > -V_S + 1.5 V$	-V _S + 1.5			-V _S + 1.5			V
Response Time	Amplifier active to shutdown		2.5			2.5		μs
	Amplifier shutdown to active		100			100		μs
Pull-Down Current	$V_{SHDN} = -V_S + 0.5 \text{ V}, T_{MIN} < T_A < T_{MAX}$		0.3	3		0.3	3	μA
	V_{SHDN} = - V_S + 1.5 V, T_{MIN} < T_A < T_{MAX}		0.6	2.5		0.6	2.5	μΑ
OUTPUT CHARACTERISTICS								
Output Voltage Swing Low	$V_{\rm OD}^3$ = 30 mV, no load		15	40		15	40	mV
•	$T_{MIN} < T_A < T_{MAX}$			45			50	mV
	V _{OD} = 30 mV, I _{SINK} = 5 mA		240	325		240	325	mV
	$T_{MIN} < T_A < T_{MAX}$			380			400	mV
Output Voltage Swing High	V _{OD} = 30 mV, no load		2.5	10		2.5	10	mV
	T _{MIN} < T _A < T _{MAX}			15			20	mV
	$V_{OD} = 30 \text{ mV}, I_{SOURCE} = 5 \text{ mA}$		570	700		570	700	mV
	T _{MIN} < T _A < T _{MAX}			1000			1100	mV

analog.com Rev. A | 6 of 31

Table 2.

			B Grad	de		H Grad	de	
Parameter	Test Conditions/Comments	Min	Тур	Max	Min	Тур	Max	Unit
Short-Circuit Current	I _{SOURCE}	20	30		20	30		mA
	$T_{MIN} < T_A < T_{MAX}$	10			6			mA
	I _{SINK}	35	45		35	45		mA
	$T_{MIN} < T_A < T_{MAX}$	10			6			mA
POWER SUPPLY								
Maximum Operating Voltage ⁴				50			50	V
V _{SY} Range	Guaranteed by PSRR	3		50	3		50	V
Supply Current per Channel	Amplifier active		40	44		40	44	μA
	$T_{MIN} < T_A < T_{MAX}$			65			70	μA
	V _{SY} = ±25 V		42	48		42	48	μA
	$T_{MIN} < T_A < T_{MAX}$			70			75	μA
	Amplifier shutdown, $V_{SHDN} = -V_S + 1.5 \text{ V}$		15	22.5		15	22.5	μΑ
	$T_{MIN} < T_A < T_{MAX}$			25			25	μA
PSRR	V _{SY} = 3 V to 50 V	123	145		123	145		dB
	$T_{MIN} < T_A < T_{MAX}$	120			120			dB
THERMAL SHUTDOWN ⁵								
Temperature	T _J		175			175		°C
Hysteresis			20			20		°C
Operating Temperature	T _A	-40		+125	-55		+150	°C

¹ Thermoelectric voltages present in the high speed production test limit the measurement accuracy of this parameter. The limits shown in Table 2 are determined by test capability and are not necessarily indicative of actual device performance.

analog.com Rev. A | 7 of 31

² Offset voltage drift is guaranteed through lab characterization and is not production tested.

 $^{^3}$ $\,$ V $_{OD}$ is +30 mV for V $_{OUT}$ high and –30 mV for V $_{OUT}$ low.

⁴ Maximum operating voltage is limited by the TDDB of the on-chip capacitor oxides. The amplifier tolerates temporary transient overshoot up to the specified absolute maximum rating and the dc supply voltage must be limited to the maximum operating voltage.

⁵ Thermal shutdown is lab characterized only and is not tested in production.

ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Rating
Supply Voltage ¹	
Transient	60 V
Continuous	50 V
Power Dissipation (P _D)	See Figure 3
Differential Input Voltage	±80 V
±IN and ±INx Pin Voltage ²	
Continuous	-10 V to +80 V
Survival	-15 V to +80 V
±IN and ±INx Pin Current ²	10 mA
SHDN and SHDNx Pin Voltage ³	-0.3 V to +60 V
Storage Temperature Range	-65°C to +150°C
Operating Temperature Range	-55°C to +150°C
Lead Temperature (Soldering, 10 sec)	300°C
T_J	175°C

- Maximum supply voltage is limited by the TDDB of the on-chip capacitor oxides. The amplifiers tolerate temporary transient overshoot up to the specified transient maximum rating. The continuous operating supply voltage must be limited to no more than 50 V.
- ½ ±IN refers to the +IN and -IN pins on the ADA4097-1, and ±INx refers to the +IN1, -IN1, +IN2, and -IN2 pins on the ADA4097-2.
- 3 SHDN is Pin 5 on the ADA4097-1, and SHDNx refers to the SHDN1 and SHDN2 pins (Pin 5 and Pin 6, respectively) on the ADA4097-2 (10-lead LFCSP).

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

 T_J exceeding 125°C promotes accelerated aging. The ADA4097-1/ ADA4097-2 demonstrate ±25 V supply operation beyond 1000 hours at T_A = 150°C.

MAXIMUM POWER DISSIPATION

The maximum safe PD on the devices is limited by the associated rise in either T_C or T_J on the die. At approximately T_C = 150°C, which is the glass transition temperature, the properties of the plastic changes. Exceeding this temperature limit, even temporarily, may change the stresses that the package exerts on the die, which permanently shifts the parametric performance of the ADA4097-1/ADA4097-2. Exceeding T_J = 175°C for an extended period may result in changes in the silicon devices and may potentially cause failure of the devices.

The P_D on the package is the sum of the quiescent power dissipation and the power dissipated in the package due to the output load drive. The quiescent power is expressed as $V_{SY} \times I_{SY}$, where I_{SY} is the quiescent current.

The P_D due to the load drive depends on the application. The P_D due to load drive is calculated by multiplying the load current by the associated voltage drop across the devices. RMS voltages and currents must be used in these calculations.

Airflow increases heat dissipation, effectively reducing θ_{JA} . Additional metal that is directly in contact with the package leads from metal traces through vias, ground, and power planes reduces θ_{JA} .

Figure 3 shows the maximum P_D vs. T_A for the single 6-lead TSOT package on a JEDEC standard, 4-layer board, with $-V_S$ connected to a pad that is thermally connected to a printed circuit board (PCB) plane. θ_{JA} values are approximations.

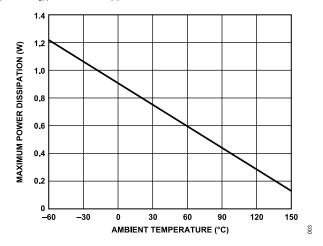


Figure 3. Maximum Power Dissipation vs. Ambient Temperature

THERMAL RESISTANCE

Thermal performance is directly linked to PCB design and operating environment. Careful attention to PCB thermal design is required.

 θ_{JA} is the junction to ambient thermal resistance, and θ_{JC} is the junction-to-case thermal resistance.

Table 4. Thermal Resistance

Package Type	θ_{JA}	θ_{JC}	Unit
UJ-6	192	51	°C/W
R-8	120	38	°C/W
RM-8	163	40	°C/W
05-08-1699	43	5.5	°C/W

ELECTROSTATIC DISCHARGE (ESD) RATINGS

The following ESD information is provided for handling of ESD-sensitive devices in an ESD protected area only.

Human body model (HBM) per ANSI/ESDA/JEDEC JS-001.

Field induced charged device model (FICDM) per ANSI/ESDA/JE-DEC JS-002.

analog.com Rev. A | 8 of 31

ABSOLUTE MAXIMUM RATINGS

ESD Ratings for ADA4097-1/ADA4097-2

Table 5. ADA4097-1 6-Lead TSOT, ADA4097-2 8-Lead SOIC_N, ADA4097-2 8-Lead MSOP, and ADA4097-2 10-Lead LFCSP

ESD Model	Withstand Threshold (kV)	Class
НВМ	±2	3A
FICDM	±1.25	3

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

analog.com Rev. A | 9 of 31

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

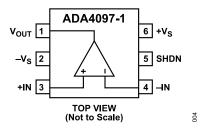


Figure 4. Pin Configuration for the ADA4097-1 6-Lead TSOT

Table 6. Pin Function Descriptions for ADA4097-1 6-Lead TSOT

Pin No.	Mnemonic	Description
1	V _{OUT}	Amplifier Output.
2	-V _S	Negative Power Supply. In single-supply applications, the $-V_S$ pin is normally soldered to a low impedance ground plane. In split-supply applications, bypass the $-V_S$ pin with a capacitance of at least 0.1 μ F to a low impedance ground plane, as close to the $-V_S$ pin as possible.
3	+IN	Noninverting Input of the Amplifier.
4	-IN	Inverting Input of the Amplifier.
5	SHDN	Op Amp Shutdown. The threshold for shutdown is approximately 1 V above the negative supply. If the SHDN pin is hard tied to $-V_S$ or floating, the amplifier is active. If the SHDN pin is asserted high ($V_{SHDN} > -V_S + 1.5 \text{ V}$), the amplifier is placed in a shutdown state, and the output of the amplifier goes to a high impedance state. If the SHDN pin is left floating, it is recommended to connect a small capacitor of 1 nF between the SHDN pin and the $-V_S$ pin to prevent signals from the $-IN$ pin from capacitively coupling to the SHDN pin.
6	+V _S	Positive Power Supply. Bypass the $+V_S$ pin with a capacitance of at least 0.1 μ F to a low impedance ground plane, as close to the $+V_S$ pin as possible.

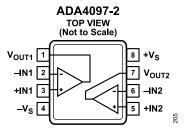


Figure 5. Pin Configuration for ADA4097-2 8-Lead SOIC_N and 8-Lead MSOP

Table 7. Pin Function Descriptions for ADA4097-2 8-Lead SOIC_N and 8-Lead MSOP

Pin No.	Mnemonic	Description
1	V _{OUT1}	Amplifier Output, Channel 1.
2	-IN1	Inverting Input of the Amplifier, Channel 1.
3	+IN1	Noninverting Input of the Amplifier, Channel 1.
4	-V _S	Negative Power Supply. In single-supply applications, the $-V_S$ pin is normally soldered to a low impedance ground plane. In split-supply applications, bypass the $-V_S$ pin with a capacitance of at least 0.1 μ F to a low impedance ground plane, as close to the $-V_S$ pin as possible.
5	+IN2	Noninverting Input of the Amplifier, Channel 2.
6	-IN2	Inverting Input of the Amplifier, Channel 2.
7	V _{OUT2}	Amplifier Output, Channel 2.
8	+V _S	Positive Power Supply. Bypass the $+V_S$ pin with a capacitance of at least 0.1 μ F to a low impedance ground plane, as close to the $+V_S$ pin as possible.

analog.com Rev. A | 10 of 31

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

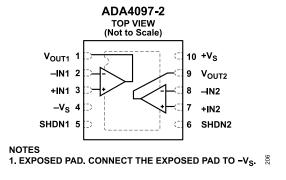


Figure 6. Pin Configuration for ADA4097-2 10-Lead LFCSP

Table 8. Pin Function Descriptions for ADA4097-2 10-Lead LFCSP

Pin No.	Mnemonic	Description			
1	V _{OUT1}	Amplifier Output, Channel 1.			
2	-IN1	Inverting Input of the Amplifier, Channel 1.			
3	+IN1	Noninverting Input of the Amplifier, Channel 1.			
4	-V _S	Negative Power Supply. In single-supply applications, the $-V_S$ pin is normally soldered to a low impedance ground plane. In split-supply applications, bypass the $-V_S$ pin with a capacitance of at least 0.1 μ F to a low impedance ground plane, as close to the $-V_S$ pin as possible.			
5	SHDN1	Op Amp Shutdown, Channel 1. The threshold for shutdown is approximately 1 V above the negative supply. If the SHDN1 pin is hard tied to $-V_S$ pin or floating, the amplifier is active. If the SHDN1 pin is asserted high ($V_{SHDN} > -V_S + 1.5 \text{ V}$), the amplifier is placed in a shutdown sta and the output of the amplifier goes to a high impedance state. If the SHDN1 pin is left floating, it is recommended to connect a small capacity of 1 nF between the SHDN1 pin and the $-V_S$ pin to prevent signals from the $-INX$ pins from capacitively coupling to the SHDN1 pin.			
6	SHDN2	Op Amp Shutdown, Channel 2. The threshold for shutdown is approximately 1 V above the negative supply. If the SHDN2 pin is hard tied to $-V_S$ pin or floating, the amplifier is active. If the SHDN2 pin is asserted high ($V_{SHDN} > -V_S + 1.5$ V), the amplifier is placed in a shutdown stat and the output of the amplifier goes to a high impedance state. If the SHDN2 pin is left floating, it is recommended to connect a small capaci of 1 nF between the SHDN2 pin and the $-V_S$ pin to prevent signals from the $-INx$ pins from capacitively coupling to the SHDN2 pin.			
7	+IN2	Noninverting Input of the Amplifier, Channel 2.			
8	-IN2	Inverting Input of the Amplifier, Channel 2.			
9	V _{OUT2}	Amplifier Output, Channel 2.			
10	+V _S	Positive Power Supply. Bypass the +V _S pin with a capacitance of at least 0.1 µF to a low impedance ground plane, as close to the +V _S pin as possible.			
	EPAD	Exposed Pad. Connect the exposed pad to -V _S .			

analog.com Rev. A | 11 of 31

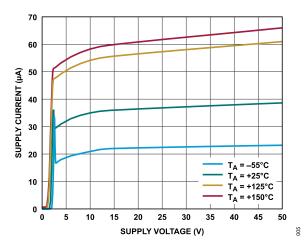


Figure 7. Supply Current vs. Supply Voltage

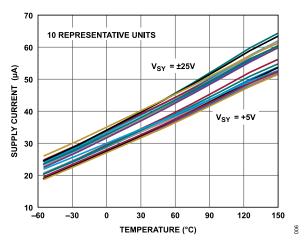


Figure 8. Supply Current vs. Temperature Across Various Supply Voltages

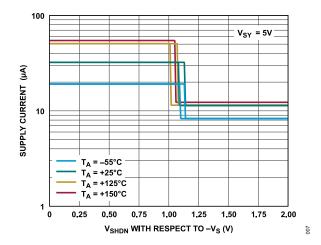


Figure 9. Supply Current vs. V_{SHDN} with Respect to $-V_S$

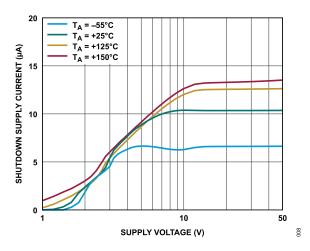


Figure 10. Shutdown Supply Current vs. Supply Voltage

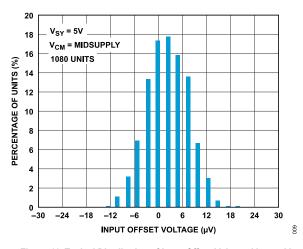


Figure 11. Typical Distribution of Input Offset Voltage, V_{SY} = 5 V

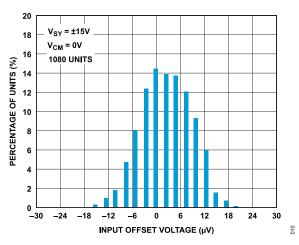


Figure 12. Typical Distribution of Input Offset Voltage with $V_{SY} = \pm 15 \text{ V}$

analog.com Rev. A | 12 of 31

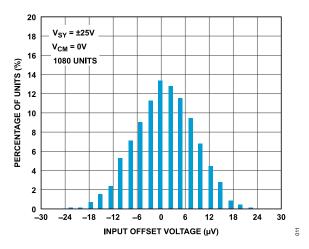


Figure 13. Typical Distribution of Input Offset Voltage with $V_{SY} = \pm 25 \text{ V}$

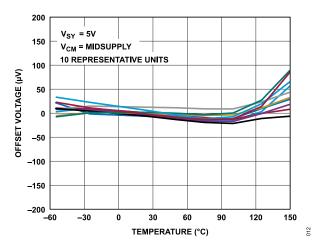


Figure 14. Midsupply Offset Voltage vs. Temperature with $V_{SY} = 5 \text{ V}$

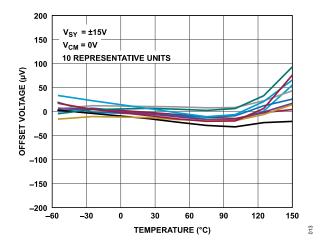


Figure 15. Offset Voltage vs. Temperature with $V_{SY} = \pm 15 \text{ V}$

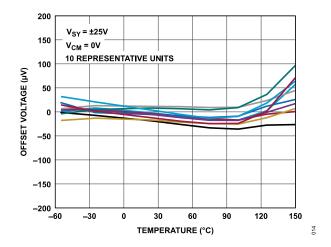


Figure 16. Offset Voltage vs. Temperature with $V_{SY} = \pm 25 \text{ V}$

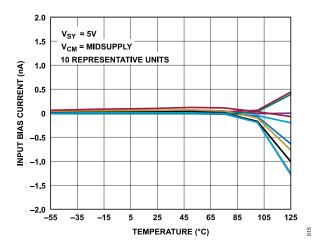


Figure 17. Midsupply Input Bias Current vs. Temperature with $V_{SY} = 5 \text{ V}$

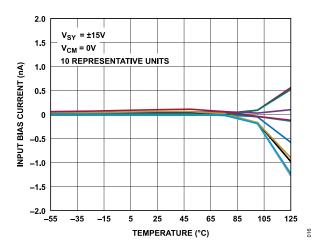


Figure 18. Input Bias Current vs. Temperature with $V_{SY} = \pm 15 \text{ V}$

analog.com Rev. A | 13 of 31

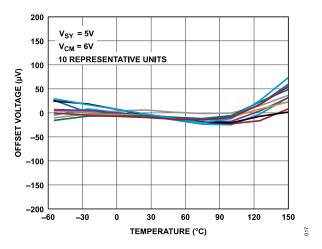


Figure 19. Offset Voltage vs. Temperature with $V_{CM} = 6 \text{ V}$, Over-The-Top

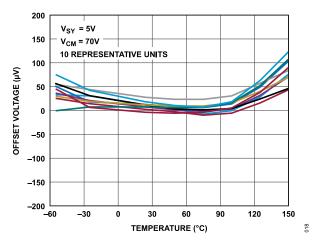


Figure 20. Offset Voltage vs. Temperature with V_{CM} = 70 V

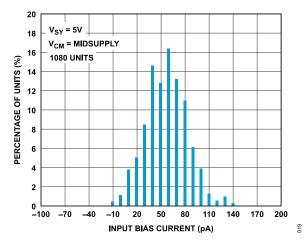


Figure 21. Typical Distribution of Input Bias Current, V_{SY} = 5 V

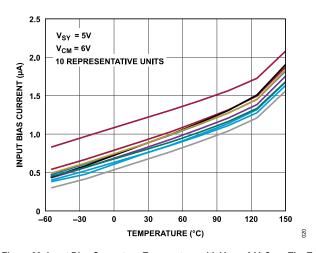


Figure 22. Input Bias Current vs. Temperature with $V_{CM} = 6 \text{ V}$, Over-The-Top

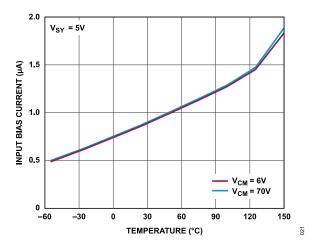


Figure 23. Input Bias Current vs. Temperature Across Various V_{CM}

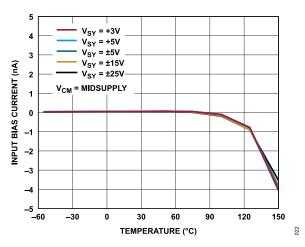


Figure 24. Input Bias Current vs. Temperature Across Various Supply Voltages

analog.com Rev. A | 14 of 31

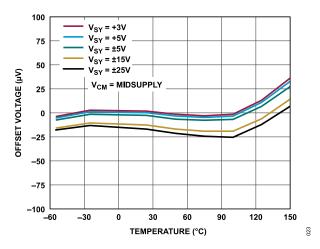


Figure 25. Offset Voltage vs. Temperature Across Various Supply Voltages

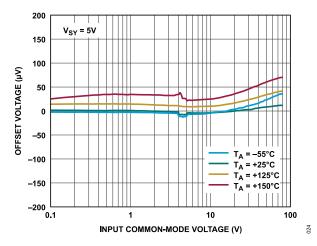


Figure 26. Offset Voltage vs. Input Common-Mode Voltage from Normal Operation to Over-The-Top Operation

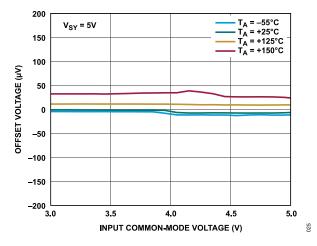


Figure 27. Offset Voltage vs. Input Common-Mode Voltage over the Input Common-Mode Range

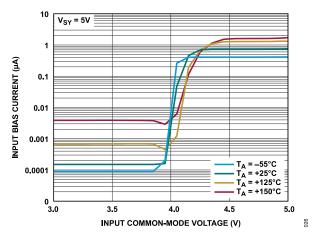


Figure 28. Input Bias Current vs. Input Common-Mode Voltage from Normal Operation to Over-The-Top Operation

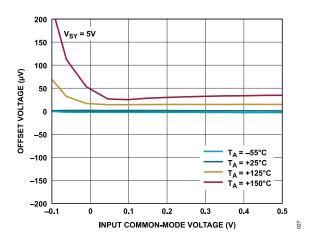


Figure 29. Offset Voltage vs. Input Common-Mode Voltage for Ground Sensing Applications

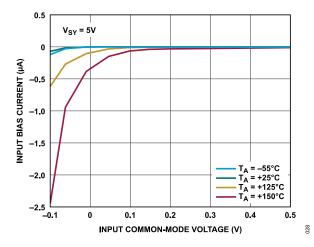


Figure 30. Input Bias Current vs. Input Common-Mode Voltage for Ground Sensing Applications

analog.com Rev. A | 15 of 31

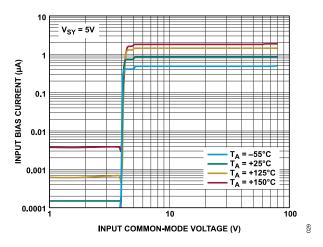


Figure 31. Input Bias Current vs. Input Common-Mode Voltage

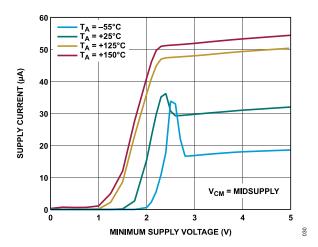


Figure 32. Supply Current vs. Minimum Supply Voltage

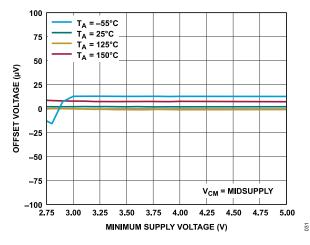


Figure 33. Offset Voltage vs. Minimum Supply Voltage

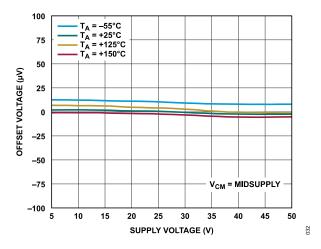


Figure 34. Offset Voltage vs. Supply Voltage

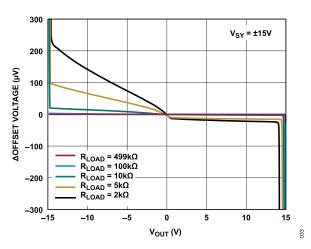


Figure 35. Δ Offset Voltage vs. V_{OUT} Across Various R_{LOAD}

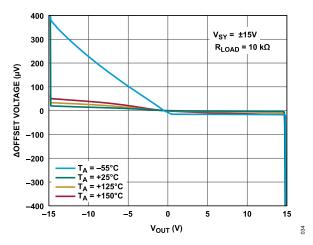


Figure 36. ΔOffset Voltage vs. V_{OUT} Across Various Temperatures

analog.com Rev. A | 16 of 31

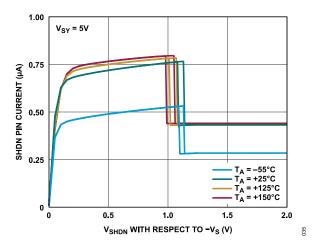


Figure 37. SHDN/SHDNx Pin Current (I_{SHDN}) vs. V_{SHDN} with Respect to $-V_S$ over Various Temperatures

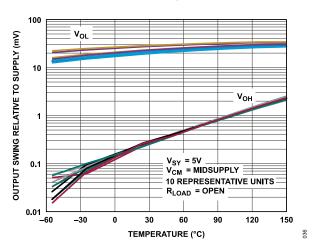


Figure 38. Output Swing Relative to Supply vs. Temperature

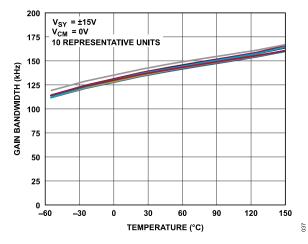


Figure 39. Gain Bandwidth vs. Temperature

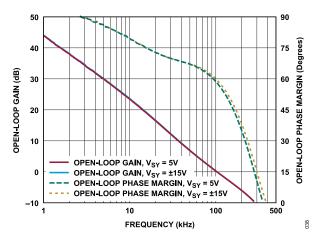


Figure 40. Open-Loop Gain and Open-Loop Phase Margin vs. Frequency

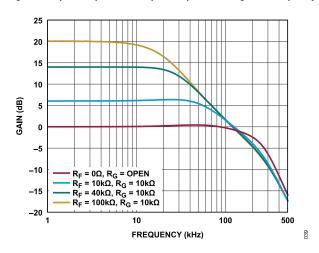


Figure 41. Noninverting Small Signal Frequency Response

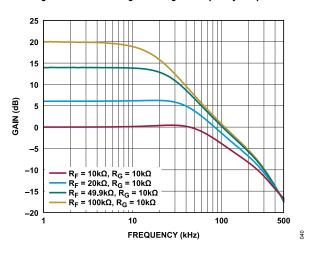


Figure 42. Inverting Small Signal Frequency Response

analog.com Rev. A | 17 of 31

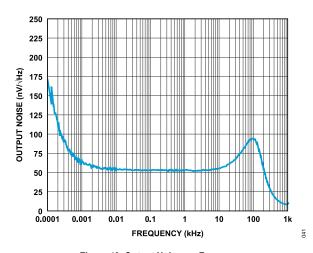


Figure 43. Output Noise vs. Frequency

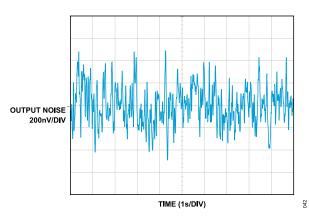


Figure 44. 0.1 Hz to 10 Hz Noise

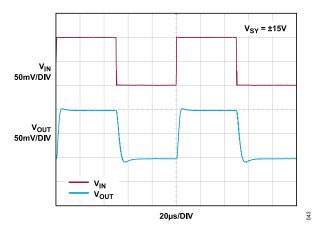


Figure 45. Unity-Gain Small Signal Step Response

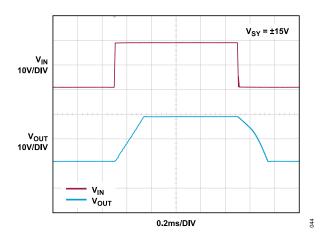


Figure 46. Unity-Gain Large Signal Step Response

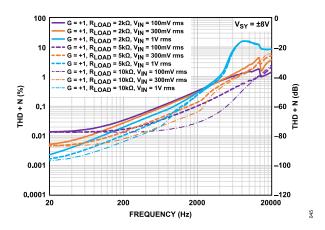


Figure 47. THD + N vs. Frequency over Load

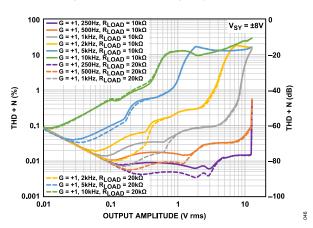


Figure 48. THD + N vs. Output Amplitude

analog.com Rev. A | 18 of 31

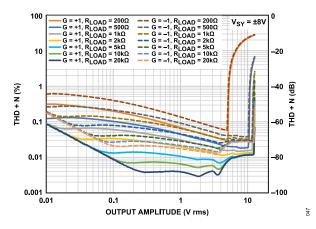


Figure 49. THD + N vs. Output Amplitude and Load

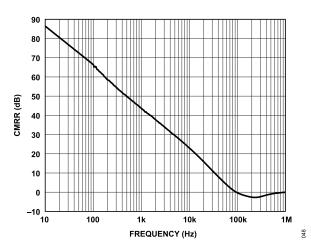


Figure 50. CMRR vs. Frequency

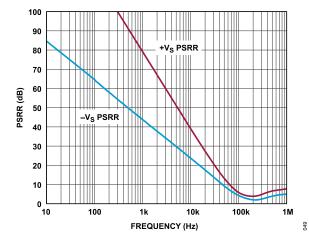


Figure 51. PSRR vs. Frequency

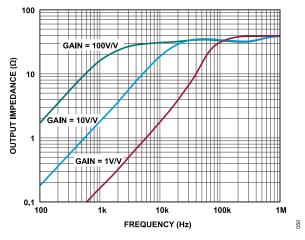


Figure 52. Output Impedance vs. Frequency

analog.com Rev. A | 19 of 31

THEORY OF OPERATION

The ADA4097-1/ADA4097-2 are robust, voltage feedback amplifiers that combine unity-gain stability with low offset, low offset drift, and 53 nV/ $\sqrt{\text{Hz}}$ of input voltage noise. Figure 55 shows a simplified schematic of the devices. The ADA4097-1/ADA4097-2 have two input stages: a common emitter differential input stage consisting of the Q1 and Q2 PNP transistors that operate with the inputs biased between $-\text{V}_{\text{S}}$ and 1 V below +V_S, and a common base input stage that consists of the Q3 to Q6 PNP transistors that operate when the common-mode input is biased >+V_S - 1 V. These input stages result in two distinct operating regions, as shown in Figure 53.

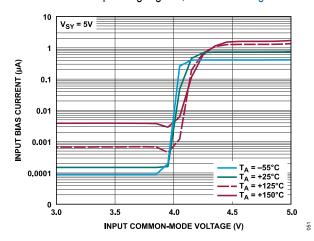


Figure 53. Input Bias Current vs. Input Common-Mode Voltage over Temperature, V_{SY} = 5 V

For common-mode input voltages that are approximately 1 V below the $\pm V_S$ supply, where Q1 and Q2 are active (see Figure 53),

the common emitter PNP input stage is active and the input bias current is typically <0.3 nA. When the common-mode input is above $+V_S-1$ V, the Q9 transistor turns on, which diverts bias current away from the common emitter differential input pair to the mirror that consists of M3 and M4. The current from M4 biases the common base differential input pair (Q3 to Q6). The Over-The-Top input pair operates in a common base configuration and the input bias current increases to ~0.8 μ A. The offset voltages of both input stages are tightly trimmed and are specified in Table 1 and Table 2.

As the input common-mode transitions to the Over-The-Top region, the input CMRR degrades slightly when compared to the rest of the input common-mode range, as shown in Figure 54.

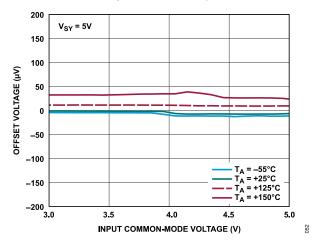


Figure 54. Offset Voltage vs. Input Common-Mode Voltage over Temperature, V_{SV} = 5 V

053

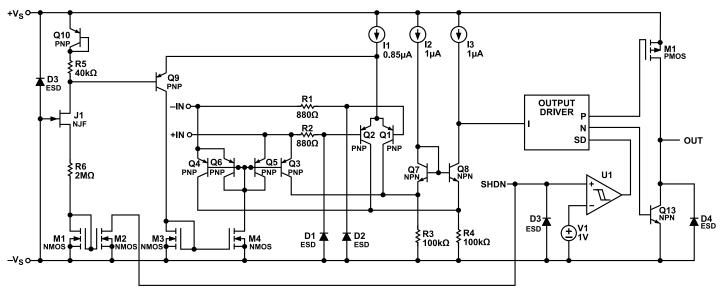


Figure 55. Simplified ADA4097-1/ADA4097-2 Schematic

analog.com Rev. A | 20 of 31

THEORY OF OPERATION

INPUT PROTECTION

The inputs are protected against temporary voltage excursions to 15 V below $-V_S$ (see Figure 56) by internal 880 Ω resistors (see Figure 55). These resistors limit the current in the series D1 diode and D2 diode that are tied to the bases of the Q1 and Q2 transistors, respectively. Adding additional external series resistance extends the protection to >15 V below $-V_S$, at the cost of stability and added thermal noise. The input stage of the ADA4097-1/ADA4097-2 incorporates phase reversal protection to prevent the output from phase reversing for inputs below $-V_S$. The ADA4097-1/ADA4097-2 op amp does not have clamping diodes between the inputs and can be differentially over-driven up to 80 V without damage, inducing parametric shifts, or drawing appreciable input current. Figure 57 summarizes the input fault types that can be applied to the ADA4097-1/ADA4097-2 without compromising input integrity.

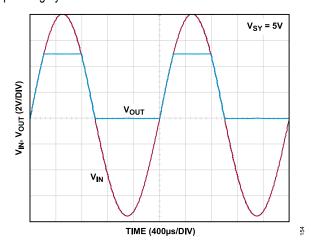


Figure 56. ADA4097-1/ADA4097-2 as Unity-Gain Buffer with Noninverting Input Driven Beyond the Supply ($V_{SY} = 5 V$)

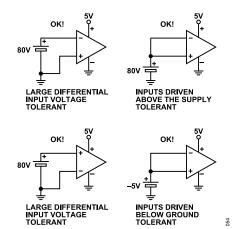


Figure 57. ADA4097-1/ADA4097-2 Fault Tolerant Conditions

OVER-THE-TOP OPERATION CONSIDERATIONS

When the ADA4097-1/ADA4097-2 input common-modes are biased near or >+V_S supply, the amplifiers operate in the Over-The-Top configuration. The differential input pair that controls amplifier operation is the common base pair, Q3 to Q6 (see Figure 55).

Input bias currents change from <±0.3 nA in normal operation to approximately 0.8 μ A in Over-The-Top operation when the input stage transitions from common emitter to common base. The Over-The-Top input bias currents are well matched, and the associated offset is typically <50 nA. Ensure that the impedance connected to the inverting and noninverting inputs is well matched to avoid any input bias current induced voltage offsets.

Differential input impedance, R_{IN} (see Figure 58), decreases from >10 M Ω in normal operation to ~60 k Ω in Over-The-Top operation (see Table 1 and Table 2).

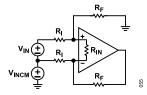


Figure 58. Difference Amplifier Configured for Normal Operation and Over-The-Top Operation (R_I Is a Gain Setting Resistor)

This R_{IN} resistance appears across the summing nodes in Over-The-Top operation due to the configuration of the common base input stage.

The R_{IN} value is derived from the specified I_{B} that flows to the op amp inputs, as expressed in the following equation:

 $R_{IN} = 2kT/(qI_B)$

where:

k is Boltzmann constant.

T is the operating temperature.

q is the charge of an electron.

 I_B is the operating input bias current in Over-The-Top operation.

The inputs are biased proportional to absolute temperature. Therefore, R_{IN} is relatively constant with temperature. This resistance appears across the summing nodes of the amplifier, which is forced to 0 V differentially by the feedback action of the amplifier and can seem relatively harmless. However, depending on the configuration, this input resistance can boost the noise gain, lower overall amplifier loop gain and closed-loop bandwidth, and raise output noise. The singular benefit of this configuration is an increase in closed-loop amplifier stability.

In normal mode ($-V_S < V_{CM} < +V_S -1 V$), R_{IN} is typically large compared to the value of the gain setting resistors (R_F and R_I), and R_{IN} can be ignored.

In this case, the noise gain is defined by the following equation:

analog.com Rev. A | 21 of 31

THEORY OF OPERATION

Noise Gain = $1 + R_F/R_I$

When the amplifiers transition to Over-The-Top operation with the input common-mode biased near or above the $+V_S$ supply, consider the value of R_{IN} .

The noise gain of the amplifiers increases as shown in the following equation:

Noise
$$Gain_{OTT} = \left(\left(1 + \frac{R_F}{R_I \mid \mid R_{IN} + R_I \mid \mid R_F}\right) \times \left(1 + \frac{R_I \mid \mid R_F}{R_{IN}}\right)\right)$$

where Noise Gain OTT is the Over-The-Top noise gain.

The dc closed-loop gain remains mostly unaffected (R_F/R_I). However, the loop gain of the amplifier decreases, as expressed in the following equation:

$$\frac{A_{OL}}{1 + \frac{R_F}{R_I}}$$
 to $\frac{A_{OL}}{Noise\ Gain_{OTT}}$

Likewise, the closed-loop bandwidth (BW_{CLOSED_LOOP}) of the amplifier changes going from normal operation to Over-The-Top operation.

In normal operation,

$$BW_{CLOSED_LOOP} \approx \frac{GBP}{1 + \frac{R_F}{R_I}}$$

In Over-The-Top operation,

$$BW_{CLOSED_LOOP} \approx \frac{GBP}{Noise\ Gain_{OTT}}$$

Output voltage noise density (e_{no}) is impacted when the device transitions from normal operation to Over-The-Top operation. Resistor noise is neglected in both modes of operation in the following equations.

In normal operation, neglecting resistor noise,

$$e_{no} \cong e_n \left(1 + \frac{R_F}{R_I}\right)$$

where e_n is input referred voltage noise density.

In Over-The-Top operation, neglecting resistor noise,

$$e_{no} \cong e_n \times Noise \ Gain_{OTT}$$

OUTPUT

The output of the ADA4097-1/ADA4097-2 can swing rail-to-rail to within 15 mV of either supply with no load. The output can source 30 mA and sink 40 mA. The amplifiers are internally compensated to drive at least 200 pF of load capacitance (C_{LOAD}). Adding a series resistance of 50 Ω between the output and larger capacitive loads extends the capacitive drive capability of the amplifier.

If the ADA4097-1/ADA4097-2 enter shutdown, the V_{OUT} (ADA4097-1) pin or the V_{OUTx} pins (ADA4097-2) appears as high impedance with two steering diodes connected to either supply. In this state, the output typically leaks <5 nA.

SHUTDOWN PINS (SHDN AND SHDNX)

The ADA4097-1/ADA4097-2 have dedicated shutdown pins (SHDN for the ADA4097-1, and SHDN1 and SHDN2 for the 10-lead LFCSP ADA4097-2 only) to place the amplifiers in a low power shutdown state when asserted high. A logic high is defined by a voltage $\geq 1.5 \ V$ applied to the SHDN pin and SHDNx pins with respect to the $-V_S$ pin. In shutdown, the amplifiers draw <20 μA of supply current (see Figure 9) and the V_{OUT} pin (ADA4097-1) or V_{OUTx} pins (ADA4097-2) are placed in a high impedance state.

The SHDN pin and SHDNx pins can be driven beyond the $+V_S$ supply up to the absolute maximum voltage (60 V with respect to $-V_S$) and draw little current (<2.5 μ A). For normal active amplifier operation, the SHDN pin and SHDNx pins can be floated or driven by an external low voltage source (within 0.5 V of $-V_S$). If the SHDN pin and SHDNx pins are left floating, an internal current source (~600 nA) pulls these pins to $-V_S$, which places the amplifiers into a default, active amplifying state. Because of the close proximity of the -IN pin (ADA4097-1) and -INx pins (ADA4097-2) and the SHDN pin and SHDNx pins, respectively, fast edges on the -IN pin and -INx pins can ac-couple to the adjacent high impedance SHDN pin and SHDNx pins, inadvertently placing the devices in shutdown. If this scenario is a concern, add a 1 nF capacitor between the SHDN pin and SHDNx pins and the $-V_S$ pin.

Alternatively, the amplifiers can be effectively placed in a low power state by removing +V $_S$. In this low power state, the inputs typically leak <1 nA with either the ±IN pins (ADA4097-1) or ±INx pins (ADA4097-2) biased between -V $_S$ and 70 V above -V $_S$. If the ±IN pins and ±INx pins are taken below -V $_S$, these pins appear as a diode connected to the -V $_S$ supply in series with a resistance of 880 Ω . In this condition, limit the current to <10 mA.

Using an external source to drive the output beyond either $\pm V_S$ supply under shutdown conditions can produce unlimited current and can damage the devices.

analog.com Rev. A | 22 of 31

LARGE RESISTOR GAIN OPERATION

The ADA4097-1/ADA4097-2 have approximately 3.5 pF of input capacitance (C_{IN}).

The parallel combination of the R_F and R_G on the inverting input can combine with C_{IN} to form a pole that can reduce bandwidth, cause frequency response peaking, or produce oscillations (see Figure 60). To mitigate these consequences, place a feedback capacitor (C_F) with a value of $C_F > C_{IN}(R_G/R_F)$ in parallel with R_F for summing node impedances >200 k Ω ($R_F||R_G > 200$ k Ω). This capacitor placement cancels the input pole and optimizes dynamic performance (see Figure 59).

For applications where the noise gain is unity $(R_G \rightarrow^\infty)$, and the feedback resistor exceeds 200 k Ω , $C_F \ge C_{IN}$. Optimize PCB layouts to keep layout related summing node capacitance to an absolute minimum.

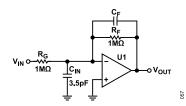


Figure 59. Inverting Gain Schematic

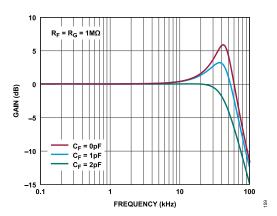


Figure 60. Inverting Gain of 1, Small Signal Frequency Response, $R_F = R_G = 1$ $M\Omega$

RECOMMENDED VALUES FOR VARIOUS GAINS

Table 9 is a reference for determining various recommended gains and associated noise performance. The total impedance seen at the inverting input is kept to <200 k Ω for gains >1 to maintain ideal small signal bandwidth.

Table 9. Gains and Associated Recommended Resistor Values (T_A = 25°C)

Gain	$R_F(k\Omega)$	$R_G(k\Omega)$	C _F (pF)	Approximate −3 dB Frequency (kHz)	Total System Noise (nV/√Hz at 1 kHz), Referred to Input
+1	0	Not applicable	Not applicable	220	53
+2	10	10	0	80	54
+2	100	100	0	100	59.5
+5	10	40.2	0	33.5	53.2
+10	10	90	0	18	53.2
-1	10	10	0	87	108
-1	100	100	0	95	119
-1	1000	1000	2	55	215
-2	10	20	0	56	80
-5	10	49.9	0	29	64.2
-10	10	100	0	17	58.5

analog.com Rev. A | 23 of 31

NOISE

To analyze the noise performance of an amplifier circuit, identify the noise sources, and then determine if each source has a significant contribution to the overall noise performance of the amplifier. To simplify the noise calculations, noise spectral densities (NSDs) are used rather than actual voltages, to leave bandwidth out of the expressions. NSD is generally expressed in nV/√Hz and is equivalent to the noise in a 1 Hz bandwidth.

The noise model shown in Figure 61 has six individual noise sources: the Johnson noise of the three resistors (R1 to R3), the op amp voltage noise, and the current noise ($I_{N\pm}$) in each input of the amplifier. Each noise source has its own contribution to the noise at the output. Noise is generally specified as referring to input (RTI), but it is often simpler to calculate the noise referred to the output (RTO), and then divide by the noise gain to obtain the RTI noise.

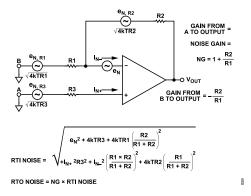


Figure 61. Op Amp Noise Analysis Model

Assuming $I_{N+} = I_{N-} = I_N$, the equation for RTI noise can be simplified to the following form:

RTI Noise =
$$\sqrt{e_n^2 + e_{n,R}^2 + \left(I_N R_{EQ}\right)^2}$$

 $e_{n,R} \sqrt{4KTR_{EQ}}$

$$R_{EQ} = R3 + R1||R2$$

where:

 e_n is the op amp voltage noise.

 $e_{n,R}$ is the thermal noise contribution of the surrounding R1 to R3 resistors.

 R_{EQ} is the equivalent input resistance.

k is Boltzmann's constant (1.38 × 10^{-23} J/K).

T is the absolute temperature in Kelvin.

A 50 Ω resistor generates a Johnson noise of 1 nV/ $\sqrt{\text{Hz}}$ at 25°C.

For optimal performance, the lower bound of resistance in a feedback network is determined by the amount of quiescent power and distortion that can be tolerated. The upper bound is determined by the resistor and current noise density. The ADA4097-1/ADA4097-2 has an e_n of 53 nV/ $\sqrt{\mbox{Hz}}$.

If resistor and current noise contributions are less than half this value, the $\mathbf{e}_{\rm n}$ introduced by the op amp dominates and provides optimal noise performance of the device.

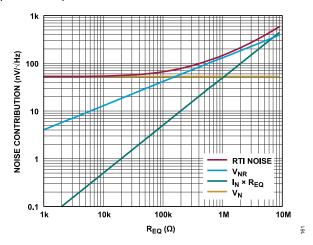


Figure 62. Noise Contributions vs. Equivalent Input Resistance

For the ADA4097-1/ADA4097-2, this lower bound of resistance in the feedback network is about 40 k Ω . For the amplifier configuration shown in Figure 61, R_{EQ} < 40 k Ω provides stable noise performance. If noise performance is not important, e_n is typically fixed for a given T_A , $e_{n,R}$ increases with the square root of the resistor value, and the $I_N \times R_{EQ}$ resistance increases linearly, but does not impact total noise until it approaches the value of $e_{n,R}$. With R_{EQ} < ~6 M Ω , $e_{n,R}$ is larger than $I_N \times R_{EQ}$. A safe value for R_{EQ} < 2 M Ω to ensure that I_N is not the majority contributor to total noise seen by the input.

Figure 62 shows the noise contributions for the range of resistance values discussed in this section.

DISTORTION

There are two main contributors of distortion in op amps: output crossover distortion as the output transitions from sourcing to sinking, and distortion caused by nonlinear common-mode rejection. If the op amp is operating in an inverting configuration, there is no common-mode induced distortion. If the op amp is operating in the noninverting configurations within the normal input common-mode range ($-V_S$ to $+V_S-1$ V), distortion is acceptable. When the inputs transition from normal to Over-The-Top operation or vice versa, a significant degradation occurs in linearity due to the change of input circuitry.

As R_{LOAD} decreases, distortion increases due to a net decrease in loop gain and greater signal swings internal to the amplifier that are necessary to drive the load. The lowest distortion can be achieved with the ADA4097-1/ADA4097-2 operating in Class A operation in an inverting configuration, with the input common-mode biased at midsupply.

analog.com Rev. A | 24 of 31

POWER DISSIPATION AND THERMAL SHUTDOWN

The ADA4097-1/ADA4097-2 can drive heavy loads on power supplies up to ± 25 V. Therefore, ensure that T_J on the IC does not exceed 175°C. See Table 4 for the θ_{JA} of each package type.

Junction temperatures exceeding 125°C promote accelerated aging. Reliability of the ADA4097-1/ADA4097-2 may be impaired if the junction temperature exceeds 175°C. If the junction temperature exceeds 175°C, the ADA4097-1/ADA4097-2 has a final safety measure in the form of a thermal shutdown that shuts off the output stage and reduces the internal device currents. When this thermal shutdown function triggers, the output remains disabled in a high impedance state until the junction temperature drops 20°C. Persistent heavy loads and elevated ambient temperatures can cause the ADA4097-1/ADA4097-2 to oscillate in and out of thermal shutdown depending on the power dissipated on the die, until the heavy load is removed (see Figure 63).

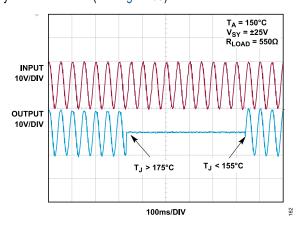


Figure 63. ADA4097-1/ADA4097-2 Cycling In and Out of Thermal Shutdown

It is not recommended to operate near the maximum junction temperature.

Typically, T_J can be estimated from T_A and the device power dissipation ($P_D \times \theta_{JA}$), as shown in the following equation:

$$T_J = T_A + P_D \times \theta_{JA}$$

The power dissipation in the IC varies as a function of supply voltage, the output voltage, and load resistance. For a given supply voltage, the worst case power dissipation $(P_{D(MAX)})$ in the IC occurs when the supply current is maximum, and the output voltage is at half of either supply voltage.

$$P_{D(MAX)} = V_S I_{S(MAX)} + \frac{\left(\frac{V_{SY}}{2}\right)^2}{\frac{R_{LOAD}}{}}$$

For a given supply voltage, use Figure 64 as a guide for estimating the minimum load resistance that the ADA4097-1/ADA4097-2 can drive for a given supply voltage and a given rise in junction temperature (ΔT_1). For example, to limit ΔT_1 to 50°C, the load driven on

the ±15 V supplies (+30 V total supply) must not be lower than 0.8 k Ω . Note that it is assumed that θ_{JA} is 192°C/W for the 6-lead TSOT package only.

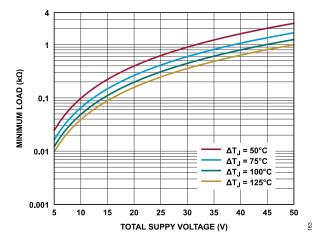


Figure 64. Minimum Load Resistance for Given ΔT_J and V_{SY}

CIRCUIT LAYOUT CONSIDERATIONS

Careful and deliberate attention to detail when laying out the ADA4097-1/ADA4097-2 boards yields optimal performance. Power supply bypassing, parasitic capacitance, and component selection all contribute to the overall performance of the amplifier.

POWER SUPPLY BYPASSING

On single supplies, solder the $-V_S$ supply pin directly to a low impedance ground plane. Bypass the $+V_S$ pin to a low impedance ground plane with a low effective series resistance (ESR) multilayer ceramic capacitor (MLCC) of 0.1 μ F, typically, as close to the $\pm V_S$ supply pins as possible. When driving heavy loads, add 10 μ F of supply capacitance. When using split supplies, these conditions are applicable to the $-V_S$ supply pin.

The ADA4097-1/ADA4097-2 have an internal current source of \sim 0.6 μ A on the SHDN pin (ADA4097-1) and the SHDNx pins (ADA4097-2, the 10-lead LFCSP only) to pull the pins down to $-V_S$ and to place the op amps in the default amplifying state. If the shutdown state is not required, hard tie the SHDN pin and the SHDNx pins to the $-V_S$ pin. If the SHDN pin and the SHDNx pins are left floating or driven by a source with significant source impedance (>100 Ω), bypass the $-V_S$ supply pin with a small, 1 nF capacitor to prevent stray signals from coupling on the SHDN pin and the SHDNx pins, which can inadvertently trigger shutdown.

GROUNDING

Use ground and power planes where possible to reduce the resistance and inductance of the supply and ground returns. Place bypass capacitors as close as possible to the $\pm V_S$ supply pins, with the other ends connected to the ground plane. It is recommended to use a bypass capacitor of at least 0.1 μF when driving light loads (load currents < 100 μA), and more capacitance when driving heavier loads. Routing from the output to the load and return to the

analog.com Rev. A | 25 of 31

ground plane must have minimal loop area to keep inductance to a minimum.

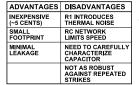
ESD PROTECTION WHEN POWERED

ICs react to ESD strikes differently when unpowered vs. powered, which falls under IEC-61000-4-2 standards (see the Absolute Maximum Ratings section). A device that performs well under HBM conditions can perform poorly under International Electrotechnical Commission (IEC) conditions. The ADA4097-1/ADA4097-2 are thoroughly abused with ESD strikes under IEC conditions to create a front-end circuit protection scheme that protects the devices if subjected to ESD strikes. Figure 65 and Figure 66 show two different protection schemes that extend the protection of the ADA4097-1/ADA4097-2 to ±8 kV ESD strikes.

Consider the following when selecting components:

- ▶ A component size of 0805 or larger to reduce chance of arc-over
- ▶ Pulse withstanding, thick film resistors
- ▶ COG MLCC with a minimum rating of 100 V
- ▶ Bidirectional, transient voltage suppression (TVS) diodes

In the circuit shown in Figure 65, R1 is a 220 Ω , Panasonic, 0805, ERJ-P6 series, and C1 is a 100 pF, Yageo, 0805, 100 V, C0G/NPO.



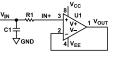


Figure 65. ESD Protection Circuit (RC Network)

Table 10. ADA4097-1/ADA4097-2 Related Products

Model	V _{OS} (μV)	I _B (nA)	GBP (kHz)	e _n (nV/√Hz)	I _{SY} (μA)	Common-Mode Input Range (V)
ADA4097-1	60	0.3	130	53	33	-V _S to -V _S + 70
ADA4097-2	60	0.3	130	53	33	$-V_S$ to $-V_S + 70$
ADA4098-1	30	0.7	1000	17	165	$-V_S$ to $-V_S + 70$
ADA4098-2	30	0.7	1000	17	165	$-V_S$ to $-V_S + 70$
ADA4099-1	30	10	8000	7	1500	$-V_S$ to $-V_S + 70$
ADA4099-2	30	10	8000	7	1500	$-V_S$ to $-V_S + 70$
ADA4077-1	35	1	3900	7	500	-V _S to +V _S
T6015	50	5	3200	18	335	$-V_S$ to $-V_S + 76$
_T6014	60	0.4	1600	9.5	165	-V _S to +V _S
T1494	375	1	2.7	185	1.5	$-V_S$ to $-V_S$ + 36
LT1490A	500	8	180	50	55	-V _S to -V _S + 44

In the circuit shown in Figure 66, R1 is a 220 Ω , Panasonic, 0805, ERJ-P6 series, and D1 is a Bourns CDSOD323-T36SC. An ESD varistor can be considered for D1.

For more information on system level ESD considerations, see the technical article, When Good Electrons Go Bad: How to Protect Your Analog Front End, on the Analog Devices, Inc., website.

ADVANTAGES	DISADVANTAGES	8I ^{Vcc}
INEXPENSIVE (20 TO 30 CENTS)	R1 INTRODUCES NOISE	V _{IN} R1 IN+ 3 U1 D_TVS V+ 1 V _{OUT}
SMALL FOOTPRINT	D1 HAS LEAKAGE CURRENT	GND 2 V-
VERY ROBUST	D1 HAS CAPACITANCE (5pF TO 300pF)	4 VEE

Figure 66. ESD Protection Circuit (R-TVS Network)

RELATED PRODUCTS

Table 10 describes several alternative precision amplifiers that can also be considered for certain applications.

analog.com Rev. A | 26 of 31

TYPICAL APPLICATIONS

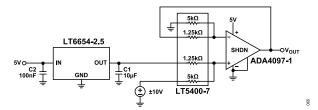


Figure 67. ±10 V to 0 V to +5 V Funnel Amplifier, High CMRR and ±80 V Input Protection via LT5400-7 Resistor Network

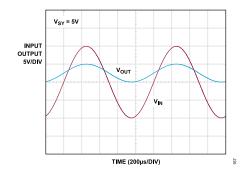


Figure 68. ±10 V to 0 V to +5 V Funnel Amplifier, Input and Output Voltages

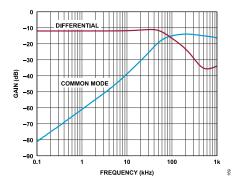


Figure 69. ±10 V to 0 V to +5 V Funnel Amplifier, System Gain

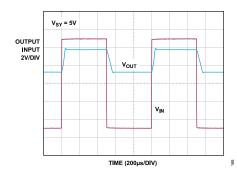


Figure 70. ±10 V to 0 V to +5 V Funnel Amplifier, Large Signal Pulse Response

analog.com Rev. A | 27 of 31

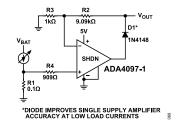


Figure 71. 1 V/A Low-Side Current Sense

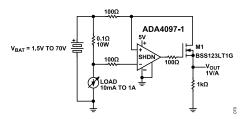


Figure 72. 1 V/A High-Side Current Sense

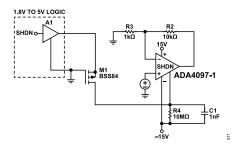


Figure 73. Microprocessor Control of SHDN Pin in Split Supply Applications

analog.com Rev. A | 28 of 31

OUTLINE DIMENSIONS

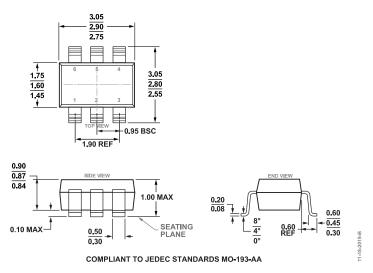
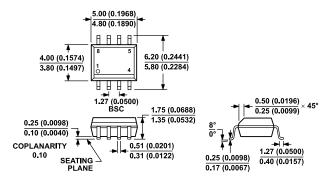


Figure 74. 6-Lead Thin Small Outline Transistor Package [TSOT]
(UJ-6)
Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MS-012-AA
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 75. 8-Lead Standard Small Outline Package [SOIC_N]
Narrow Body
(R-8)

Dimensions shown in millimeters and (inches)

analog.com Rev. A | 29 of 31

OUTLINE DIMENSIONS

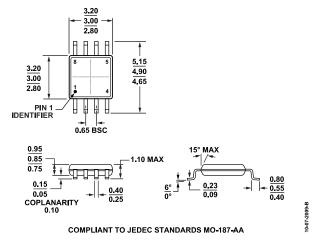


Figure 76. 8-Lead Mini Small Outline Package [MSOP] (RM-8) Dimensions shown in millimeters

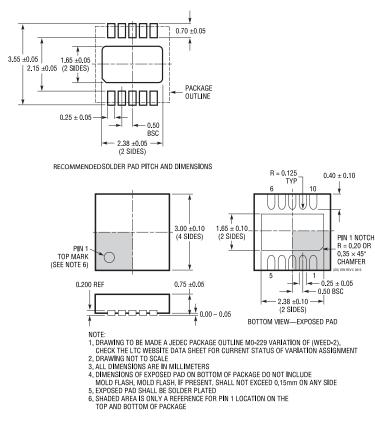


Figure 77. 10-Lead Lead Frame Chip Scale Package [LFCSP] 3 mm × 3 mm Body and 0.75 mm Package Height (05-08-1699) Dimensions shown in millimeters

analog.com Rev. A | 30 of 31

OUTLINE DIMENSIONS

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Packing Quantity	Package Option	Marking Code
ADA4097-1BUJZ-R5	-40°C to +125°C	6-Lead TSOT	Reel, 500	UJ-6	Y7K
ADA4097-1BUJZ-RL7	-40°C to +125°C	6-Lead TSOT	Reel, 2500	UJ-6	Y7K
ADA4097-1HUJZ-RL7	-55°C to +150°C	6-Lead TSOT	Reel, 2500	UJ-6	Y7L
ADA4097-2BCPZ	-40°C to +125°C	10-Lead LFCSP	Tube, 121	05-08-1699	A48
ADA4097-2BCPZ-RL7	-40°C to +125°C	10-Lead LFCSP	Reel, 2500	05-08-1699	A48
ADA4097-2BRMZ	-40°C to +125°C	8-Lead MSOP	Tube, 50	RM-8	A48
ADA4097-2BRMZ-RL7	-40°C to +125°C	8-Lead MSOP	Reel, 2500	RM-8	A48
ADA4097-2BRZ	-40°C to +125°C	8-Lead SOIC_N	Tube, 100	R-8	
ADA4097-2BRZ-RL7	-40°C to +125°C	8-Lead SOIC_N	Reel, 2500	R-8	
ADA4097-2HCPZ	-55°C to +150°C	10-Lead LFCSP	Tube, 121	05-08-1699	A49
ADA4097-2HCPZ-RL7	-55°C to +150°C	10-Lead LFCSP	Reel, 2500	05-08-1699	A49
ADA4097-2HRZ	-55°C to +150°C	8-Lead SOIC_N	Tube, 100	R-8	
ADA4097-2HRZ-RL7	v55°C to +150°C	8-Lead SOIC_N	Reel, 2500	R-8	

¹ Z = RoHS Compliant Part.

EVALUATION BOARDS

Model ¹	Description
EVAL-ADA4097-1HUJZ	Evaluation Board, Single TSOT
EVAL-ADA4097-2EBZ	Evaluation Board, Dual LFCSP

¹ Z = RoHS Compliant Part.

